

FJNS3207RBU

FJNS3207RBU Information



Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



FJNS3207RBU Specifications

Manufacturer Part Number	FJNS3207RBU
Manufacturer	Fairchild/ON Semiconductor
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - Single, Pre-Biased
Package	TO-226-3, TO-92-3 Short Body (Formed Leads)
Series	-
Transistor Type	NPN - Pre-Biased
Current - Collector (Ic) (Max)	100mA
Voltage - Collector Emitter Breakdown (Max)	50V
Resistor - Base (R1) (Ohms)	22k
Resistor - Emitter Base (R2) (Ohms)	47k
DC Current Gain (hFE) (Min) @ Ic, Vce	68 @ 5mA, 5V
Vce Saturation (Max) @ Ib, Ic	300mV @ 500µA, 10mA
Current - Collector Cutoff (Max)	100nA (ICBO)
Frequency - Transition	250MHz
Power - Max	300mW
Mounting Type	Through Hole
Package / Case	TO-226-3, TO-92-3 Short Body (Formed Leads)
Supplier Device Package	TO-92S
	Report errors?

FJNS3207RBU Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE UARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

FJNS3207RBU Payment Methods



FJNS3207RBU Shipping Methods



If you have any question about FJNS3207RBU, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com